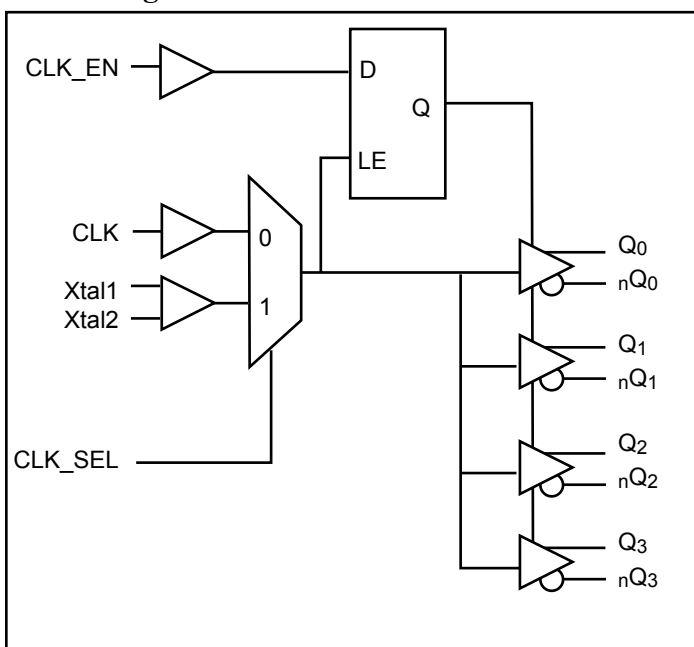# 3.3V Low Skew 1-to-4
Crystal/LVCMOS to LVPECL Fanout Buffer

Features

- Maximum operation frequency: 500MHz
- 4 pair of differential LVPECL outputs
- Selectable CLK and crystal inputs
- CLK accepts LVCMOS, LVTTL input level
- Output Skew: 30ps (maximum)
- Part-to-part skew: 150ps (maximum)
- Propagation delay: 1.5ns (maximum)
- 3.3V power supply
- Pin-to-pin compatible to ICS8535-11
- Operating Temperature: -40°C to 85°C
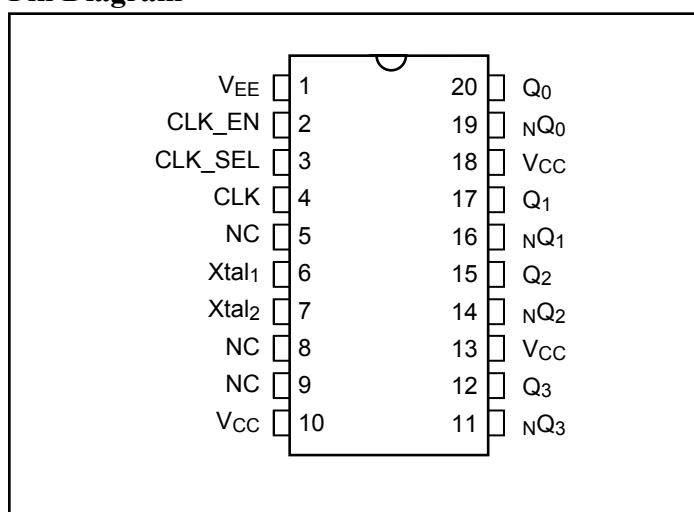- Packaging (Pb-free & Green available**)**:
  - 20-pin TSSOP (L)

Description

The PI6C48535-11 is a high-performance low-skew LVPECL fanout buffer. PI6C48535-11 features selectable of single-ended clock or crystal inputs and translates to four LVPECL outputs. The CLK input accepts LVCMOS or LVTTL signals. The outputs are synchronized with input clock during asynchronous assertion /deassertion of CLK_EN pin. PI6C48535-11 is ideal for crystal or LVCMOS/LVTTL to LVPECL translation. Typical clock translation and distribution applications are data-communications and telecommunications.

Block Diagram

Pin Diagram

Pin Description

Name	Pin #	Type	Description
V_{EE}	1	P	Connect to Negative power supply
CLK_EN	2	I_PU	Synchronizing clock enable. When high, clock outputs follow clock input. When low, Q_x outputs are forced low, nQ_x outputs are forced high. LVCMOS/LVTTL level with 50KΩ pull up.
CLK_SEL	3	I_PD	Clock select input. When high, selects CLK_1 input. When low, selects CLK_0 input. LVCMOS/LVTTL level with 50KΩ pull down.
CLK	4	I_PD	LVCMOS / LVTTL clock input
Xtal1, Xtal2	6, 7		Crystal input and output
NC	5, 8, 9		No internal connection.
V_{CC}	10, 13, 18	P	Connect to 3.3V
Q_3, nQ_3	11, 12	O	Differential output pair, LVPECL interface level.
Q_2, nQ2	14, 15	O	Differential output pair, LVPECL interface level.
Q_1, nQ_1	16, 17	O	Differential output pair, LVPECL interface level.
Q_0, nQ_0	19, 20	O	Differential output pair, LVPECL interface level.

Notes:

1. I = Input, O = Output, P = Power supply connection, I_PD = Input with pull down, I_PU = Input with pull up

Pin Characteristics

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
C_{IN}	Input Capacitance				4	pF
R_pullup	Input Pullup Resistance			50		KΩ
R_pulldown	Input Pulldown Resistance			50		KΩ

Control Input Function Table

Inputs			Outputs	
CLK_EN	CLK_SEL	Selected Source	Q_0:Q_3	nQ_0:nQ_3
0	0	CLK	Diasbled: Low	Diasbled: High
0	1	Xtal1, Xtal2	Disabled: Low	Disabled: High
1	0	CLK	Enabled	Enabled
1	1	Xtal1, Xtal2	Enabled	Enabled

Notes:

1. After CLK_EN switches, the clock outputs are disabled or enabled following a rising and falling input clock edge as show below.

Figure 1. CLK_EN Timing Diagram
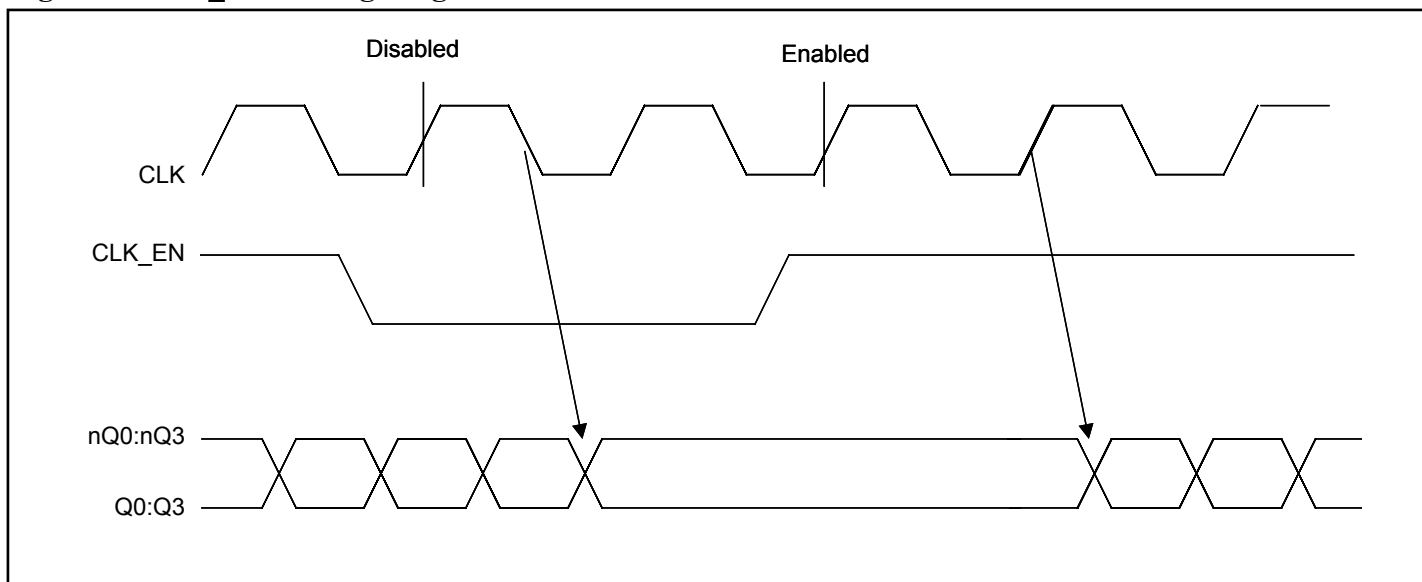
Clock Input Function Table

Inputs	Outputs	
CLK	$Q_0{:}Q_3$	$nQ_0{:}nQ_3$
0	LOW	HIGH
1	HIGH	LOW

Absolute Maximum Ratings

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V_{CC}	Supply voltage	Referenced to GND			4.6	
V_{IN}	Input voltage	Referenced to GND	-0.5		V_{CC} +0.5V	V
V_{OUT}	Output voltage	Referenced to GND	-0.5		V_{CC} +0.5V	
T_{STG}	Storage temperature		-65		150	^{o}C

Notes:
1. Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress speci-fications only and correct functional operation of the device at these or any other conditions above those listed in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Operating Conditions

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V_{CC}	Power Supply Voltage		3.0	3.3	3.6	V
T_A	Ambient Temperature		-40		85	^{o}C
I_{EE}	Power Supply Current				60	mA

LVCMOS/LVTTL DC Characteristics (T_A = -40°C to 85°C, V_{CC} = 3.0V to 3.6V unless otherwise stated below.)

Symbol	Parameter		Conditions	Min	Typ	Max	Units
V_{IH}	Input High Voltage			2		V_{CC}+0.3	V
V_{IL}	Input Low Voltage			-0.3		0.8	
I_{IH}	Input High Current	CLK, CLK_SEL	V_{IN} = V_{CC} = 3.6V			150	μA
		CLK_EN	V_{IN} = V_{CC} = 3.6V			5	
I_{IL}	Input Low Current	CLK, CLK_SEL	V_{IN} = 0V, V_{CC} = 3.6V	-5			
		CLK_EN	V_{IN} = 0V, V_{CC} = 3.6V	-150			

LVPECL DC Characteristics (T_A = -40°C to 85°C, V_{CC} = 3.0V to 3.6V unless otherwise stated below.)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V_{OH}	Output High Voltage[1]		V_{CC}-1.4		V_{CC}-0.9	
V_{OL}	Output Low Voltage[1]		V_{CC}-2.0		V_{CC}-1.7	V
V_{SWING}	Peak-to-peak Output Voltage Swing		0.6		1.0	

Notes:

1. Outputs terminated with 50Ω to V_{CC}-2.0V

Crystal Characteristics

Parameter	Min.	Typ.	Max.	Units
Mode of Oscillation		Fundamental		
Frequency Range	14		25	MHz
Equivalent Series Resistance (ESR)			70	Ω
Shunt Capacitance			7	pF

AC Characteristics (T_A = -40°C to 85°C, V_{CC} = 3.0V to 3.6V)

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
f_{max}	Output Frequency				500	MHz
t_{Pd}	Propagation Delay[1]		1.0		1.5	ns
Tsk(o)	Output-to-output Skew[2]				30	
Tsk(pp)	Part-to-part Skew[3]				150	ps
t_r/t_f	Output Rise/Fall time	20% - 80%	100		400	
odc	Output duty cycle		48		52	%
Osc	Crystal Tolerance				1000	ppm

Notes:

1. Measured from the V_{CC}/2 of the input to the differential output crossing point
2. Defined as skew between outputs at the same supply voltage and with equal load condition. Measured at the outputs differential crossing point.
3. Defined as skew between outputs on different parts operating at the same supply voltage and with equal load condition. Measured at the outputs differential crossing point.
4. All parameters are measured at 500MHz unless noted otherwise

Packaging Mechanical: 20-Pin TSSOP (L)
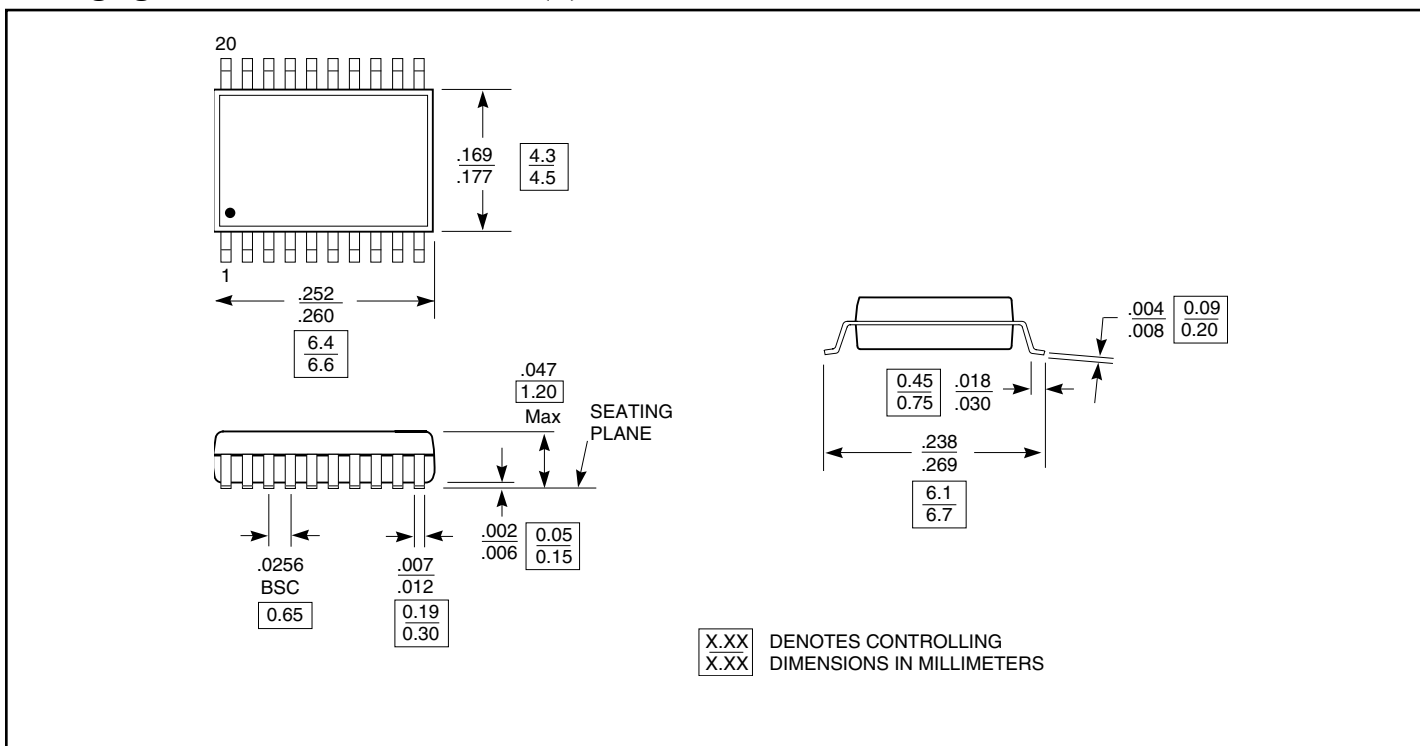
Ordering Information

Ordering Code	Package Code	Package Description
PI6C48535-11LE	L	Pb-free & Green 20-pin 173-mil wide TSSOP

Notes:

1. Thermal characteristics can be found on the company web site at www.pericom.com/packaging/

2. Number of Transistors = TBD